LM8050I, LM8050J

Amplifier Transistors

NPN Silicon



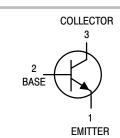
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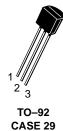
http://onsemi.com

MAXIMUM RATINGS Rating Symbol Value Unit Vdc Collector-Emitter Voltage VCEO 25 Collector-Base Voltage V_{CBO} 30 Vdc Emitter-Base Voltage VEBO 6.0 Vdc Collector Current - Continuous I_C 800 mAdc Total Device Dissipation P_D @ $T_A = 25^{\circ}C$ 625 mW Derate above 25°C mW/°C 5.0 **Total Device Dissipation** P_D @ $T_{C} = 25^{\circ}C$ 1.5 Watts Derate above 25°C 12 mW/°C Operating and Storage Junction °C -55 to T_J, T_{stg} Temperature Range +150

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Ambient	$R_{ hetaJA}$	200	°C/W
Thermal Resistance, Junction to Case	$R_{ extsf{ heta}JC}$	83.3	°C/W





CASE 29 STYLE 1

MARKING DIAGRAMS



LM8050x = Specific Device Code

= I or J

х

Υ

= Year

WW = Work Week

ORDERING INFORMATION

Device	Package Shipping	
LM8050I	TO-92	5000 Units/Box
LM8050J	TO-92	5000 Units/Box

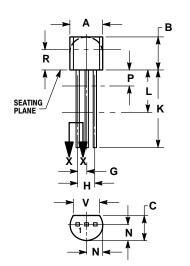
LM8050I, LM8050J

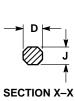
ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
Collector–Emitter Breakdown Voltage $(I_C = 1.0 \text{ mAdc}, I_B = 0)$	V _{(BR)CEO}	25	-	-	Vdc
Collector–Base Breakdown Voltage $(I_C = 0.5 \text{ mAdc}, I_E = 0)$	V _{(BR)CBO}	30	-	-	Vdc
Emitter–Base Breakdown Voltage ($I_E = 0.1 \text{ mAdc}, I_C = 0$)	V _{(BR)EBO}	6.0	-	-	Vdc
Collector Cutoff Current ($V_{CB} = 15 \text{ Vdc}, I_E = 0$)	I _{CBO}	_	-	50	nAdc
ON CHARACTERISTICS	·				
DC Current Gain ($I_C = 50 \text{ mAdc}, V_{CE} = 1.0 \text{ Vdc}$) ($I_C = 350 \text{ mAdc}, V_{CE} = 1.0 \text{ Vdc}$) LM8050J	h _{FE}	100 150 60	- - -	200 300 -	-
Collector–Emitter Saturation Voltage ($I_C = 500 \text{ mAdc}, I_B = 50 \text{ mAdc}$)	V _{CE(sat)}	-	-	0.5	Vdc
Base–Emitter Saturation Voltage ($I_C = 500 \text{ mAdc}, I_B = 50 \text{ mAdc}$)	V _{BE(sat)}	-	-	1.2	Vdc

PACKAGE DIMENSIONS

TO-92 (TO-226) CASE 29-11 **ISSUE AL**





NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH. 3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED. 4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INC	HES	MILLIM	ETERS
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.20
В	0.170	0.210	4.32	5.33
С	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
Κ	0.500		12.70	
Ĺ	0.250		6.35	
Ν	0.080	0.105	2.04	2.66
Ρ		0.100		2.54
R	0.115		2.93	
٧	0.135		3.43	

STYLE 1: PIN 1. EMITTER 2. BASE 3. COLLECTOR

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